

#### **Features**

- High Dense Cell Design for Extremely Low R<sub>DS(ON)</sub>
- · Voltage Controlled Small Signal Switch
- · Surface Mount Package
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

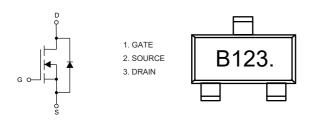
## **Maximum Ratings**

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Thermal Resistance: 357°C/W Junction to Ambient

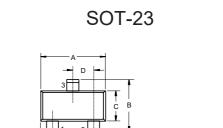
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	$V_{GS}$	±20	V
Drain Current-Continuous	I <sub>D</sub>	0.17	Α
Drain Current-Pulsed	I <sub>DM</sub>	0.68	Α
Power Dissipation	P <sub>D</sub>	0.35	W

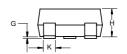
Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## **Internal Structure and Marking Code**



# **N-Channel MOSFET**

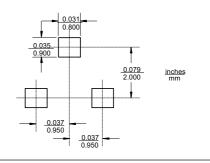






DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.110	0.120	2.80	3.04		
В	0.083	0.104	2.10	2.64		
С	0.047	0.055	1.20	1.40		
D	0.034	0.041	0.85	1.05		
E	0.067	0.083	1.70	2.10		
F	0.018	0.024	0.45	0.60		
G	0.0004	0.006	0.01	0.15		
Н	0.035	0.043	0.90	1.10		
J	0.003	0.007	0.08	0.18		
K	0.012	0.020	0.30	0.51		
L	0.007	0.020	0.20	0.50		

#### **Suggested Solder Pad Layout**





# **ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

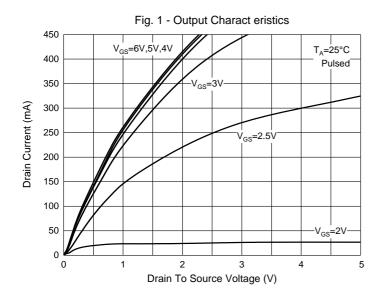
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Static Characteristics			<u> </u>			
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	100			V
Gate-Threshold Voltage <sup>(Note2)</sup>	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.0		2.8	V
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =± 20V, V <sub>DS</sub> =0V			±50	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V V <sub>DS</sub> =20V, V <sub>GS</sub> =0V			1	μA
Drain-Source On-Resistance <sup>(Note2)</sup>		V <sub>DS</sub> =20V, V <sub>GS</sub> =0V V <sub>GS</sub> =10V, I <sub>D</sub> =0.17A		10		nA
	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =0.17A			10	
Forward Transconductance <sup>(Note2)</sup>	g <sub>FS</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =0.17A	80			mS
Diode Forward Voltage <sup>(Note2)</sup>	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =0.34A			1.3	V
Dynamic Characteristics(Note4)	1			1		
Input Capacitance	C <sub>iss</sub>			29	60	pF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V, f=1MHz		10	15	
Reverse Transfer Capacitance	C <sub>rss</sub>			2	6	
Switching Characteristics						
Total Gate Charge	Qg			1.4	2	
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =10V,V <sub>GS</sub> =10V,I <sub>D</sub> =0.22A		0.15	0.25	nC
Gate-Drain Charge	$Q_{gd}$			0.2	0.4	
Turn-On Delay Time <sup>(Note3,4)</sup>	t <sub>d(on)</sub>				8	
Turn-On Rise Time <sup>(Note3,4)</sup>	t <sub>r</sub>	$V_{DD} = 30V, V_{GS} = 10V, R_{G} = 50\Omega,$			8	
Turn-Off Delay Time <sup>(Note3,4)</sup>	t <sub>d(off)</sub>	I <sub>D</sub> =0.28A			13	ns
Turn-Off Fall Time <sup>(Note3,4)</sup>	t <sub>f</sub>				16	

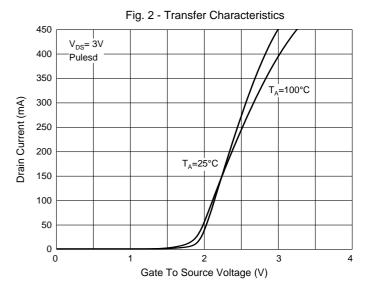
### Note:

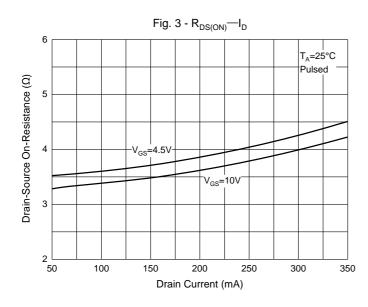
- 2. Pulse Test : Pulse Width=300 $\mu$ s, Duty Cycle≤2%.
- 3. Switching Characteristics are Independent of Operating Junction Temperature.
- 4. Graranted by Design, Not Subject to Producting.

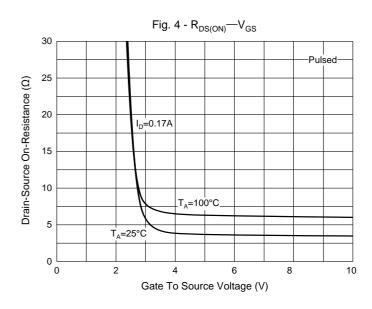


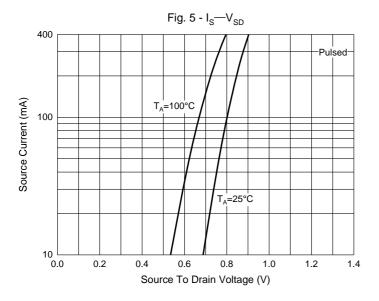
#### **Curve Characteristics**

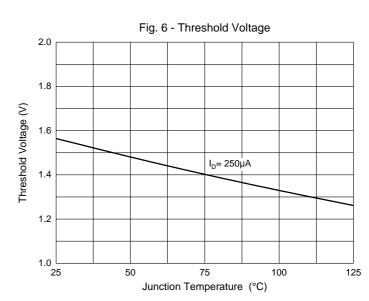














### **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel

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